# NSN 5962-01-293-0133

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-293-0133

# **Body Length:**

Between 1.230 inches and 1.285 inches

# **Body Width:**

Between 0.510 inches and 0.545 inches

# **Body Height:**

Between 0.090 inches and 0.210 inches

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and burn in and programmable and bipolar and high performance

#### **Inclosure Material:**

Ceramic

#### Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

14 input

**Terminal Surface Treatment:** 

Solder

#### Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### **Time Rating Per Chacteristic:**

40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

---

## Demilitarization:

Yes - demil/mli

#### Fiig:

A458a0